





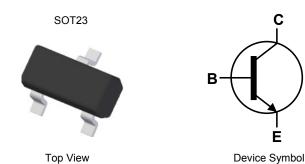
### **45V NPN SMALL SIGNAL TRANSISTOR IN SOT23**

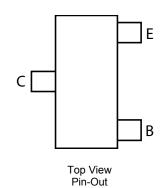
### **Features**

- BV<sub>CEO</sub> > 45V
- I<sub>C</sub> = 800mA High Continuous Collector Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < 300mV @ 100mA</li>
- Complementary PNP Type: BCW68H
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

### **Mechanical Data**

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>3</sup>
- Weight 0.008 grams (approximate)





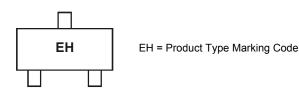
### Ordering Information (Notes 4 & 5)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BCW66HTA	AEC-Q101	EH	7	8	3,000
BCW66HQTA	Automotive	EH	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**





Maximum Ratings (@TA = +25°C, unless otherwise specified.)

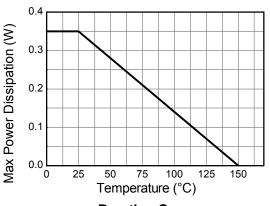
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	75	V
Collector-Emitter Voltage	V <sub>CEO</sub>	45	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	800	mA
Peak Pulse Current	I <sub>CM</sub>	1000	mA
Base Current	I <sub>B</sub>	100	mA

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

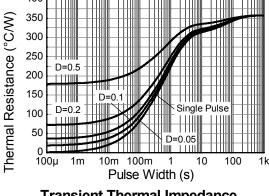
Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 6)	D	310	mW	
Power Dissipation	(Note 7)	P <sub>D</sub>	350	IIIVV	
Thermal Resistance, Junction to Ambient	(Note 6)	Б	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 7)	R <sub>0JA</sub>	K <sub>0</sub> JA 357		
Thermal Resistance, Junction to Leads	(Note 8)	R <sub>0JL</sub>	350	°C/W	
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C	

Notes:

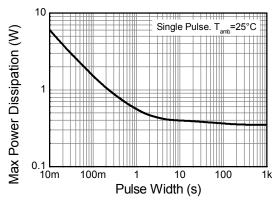
- 6. For a device mounted on minimum recommended pad layout 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Same as Note 6, except the device is mounted on 15mm X 15mm 1oz copper.
- 8. Thermal resistance from junction to solder-point (at the end of the leads).



## **Derating Curve**



**Transient Thermal Impedance** 



**Pulse Power Dissipation** 



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

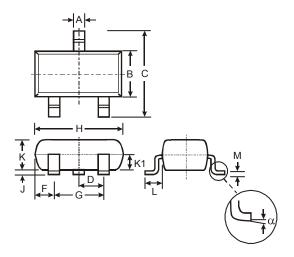
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	$BV_{CES}$	75	_	_	V	$I_C = 10\mu A$
Collector-Emitter Breakdown Voltage (base open) (Note 9)	BV <sub>CEO</sub>	45	_	_	V	I <sub>CEO</sub> = 10mA
Emitter-Base Breakdown Voltage	$BV_{EBO}$	7	_	_	V	I <sub>EBO</sub> = 10μA
Collector-Emitter Cut-Off Current	I <sub>CES</sub>		<1 —	20 20	nΑ μΑ	V <sub>CES</sub> = 45V V <sub>CES</sub> = 45V, T <sub>A</sub> = +150°C
Emitter-Base Cut-Off Current	I <sub>EBO</sub>	_	<1	20	nA	V <sub>EBO</sub> = 5.6V
ON CHARACTERISTICS (Note 9)	•		•	•	•	
Static Forward Current Transfer Ratio	h <sub>FE</sub>	80 180 250 100	 350 	 630 	_	$I_C = 100\mu A, V_{CE} = 10V$ $I_C = 10mA, V_{CE} = 1V$ $I_C = 100mA, V_{CE} = 1V$ $I_C = 500mA, V_{CE} = 2V$
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	_		0.3 0.7	mV	$I_C = 100 \text{mA}, I_B = 10 \text{mA}$ $I_C = 500 \text{mA}, I_B = 50 \text{mA}$
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>		_	2	V	I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA
SMALL SIGNAL CHARACTERISTICS (Note 9)	. , ,		•	•		
Transition Frequency	f⊤	100	_	_	MHz	$I_C = 20$ mA, $V_{CE} = 10$ V, f = 100MHz
Output Capacitance	Cobo	-	8	12	pF	V <sub>CB</sub> = 10V, f = 1MHz
Input Capacitance	C <sub>ibo</sub>	_	_	80	pF	$V_{CB} = -0.5V, f = 1MHz$
Noise Figure	N	_	2	10	dB	$I_C$ = 0.2mA. $V_{CE}$ = 5V, $R_G$ = 1K $\Omega$
Turn-On Time	t <sub>on</sub>		_	100	ns	I <sub>C</sub> = 150mA.
Turn-Off Time	t <sub>off</sub>	_	_	400	ns	$I_{B1} = -I_{B2} = 15\text{mA}$ $R_L = 150\Omega$

Notes: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%



# **Package Outline Dimensions**

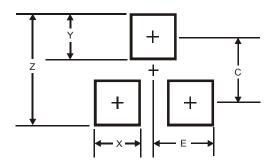
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23				
Dim	Min	Max	Тур	
Α	0.37	0.51	0.40	
В	1.20	1.40	1.30	
С	2.30	2.50	2.40	
D	0.89	1.03	0.915	
F	0.45	0.60	0.535	
G	1.78	2.05	1.83	
Н	2.80	3.00	2.90	
7	0.013	0.10	0.05	
K	0.903	1.10	1.00	
K1	-	-	0.400	
L	0.45	0.61	0.55	
М	0.085	0.18	0.11	
α	0°	8°	-	
All Dimensions in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	2.9		
X	0.8		
Υ	0.9		
С	2.0		
E	1.35		





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